

## 256 Microstepping Motor Driver

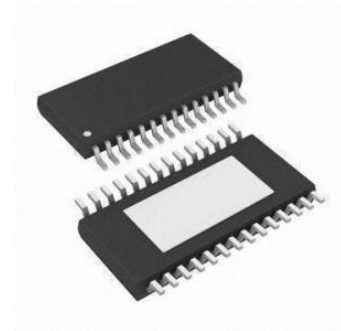
### PRODUCT DESCRIPTION

The MS4998 is a bipolar microstepping driver with built-in 8bit DAC, which can achieve eight step modes: full, 1/2, 1/4, 1/8, 1/16, 1/64, 1/128, 1/256 step. And the MS4998 has the maximum driving capacity of 35V,  $\pm 1.5A$ .

The MS4998 is pulse control mode, that every time the step pin is applied to one pulse, the motor would move one microstep without phase sequence table, high-frequency control line and complex program control interface.

In addition, the MS4998 has the regulator of fixed current decay period, automatically selecting current decay mode, slow and mixed decay. The mixed decay is fast decay in previous time and slow decay in remaining time. This decay mode contributes to improve step accuracy, reduce motor noise and power dissipation.

The internal synchronous rectification circuit could reduce power dissipation. The MS4998 has thermal shutdown(TSD), overcurrent protection(OCP), undervoltage lockout(UVLO) and shorted protection and it doesn't need special power-on process.



eTSSOP28

### FEATURES

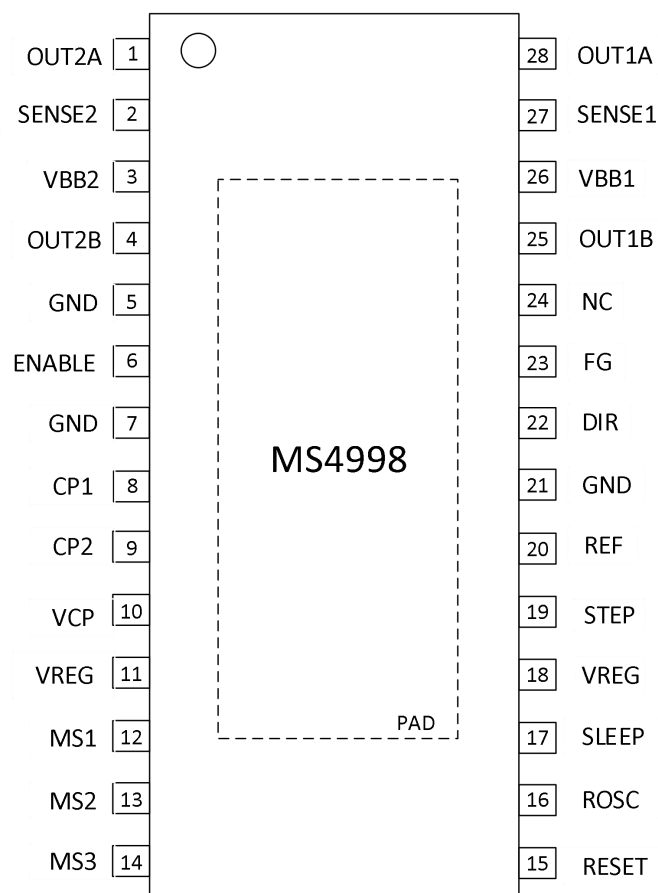
- Low Output On-resistance
- Automatic Current Decay Mode Selection and Detection
- Synchronous Rectification
- Mixed and Sloe Mode
- Compatible with Logic Input for 5V and 3.3V
- Thermal Shutdown, Undervoltage Lockout
- Low Current Sleep Mode(<50uA)

### APPLICATIONS

- Security and Protection Video Monitoring
- 3D Print
- Robot Technology
- Industry Application

### PRODUCT SPECIFICATION

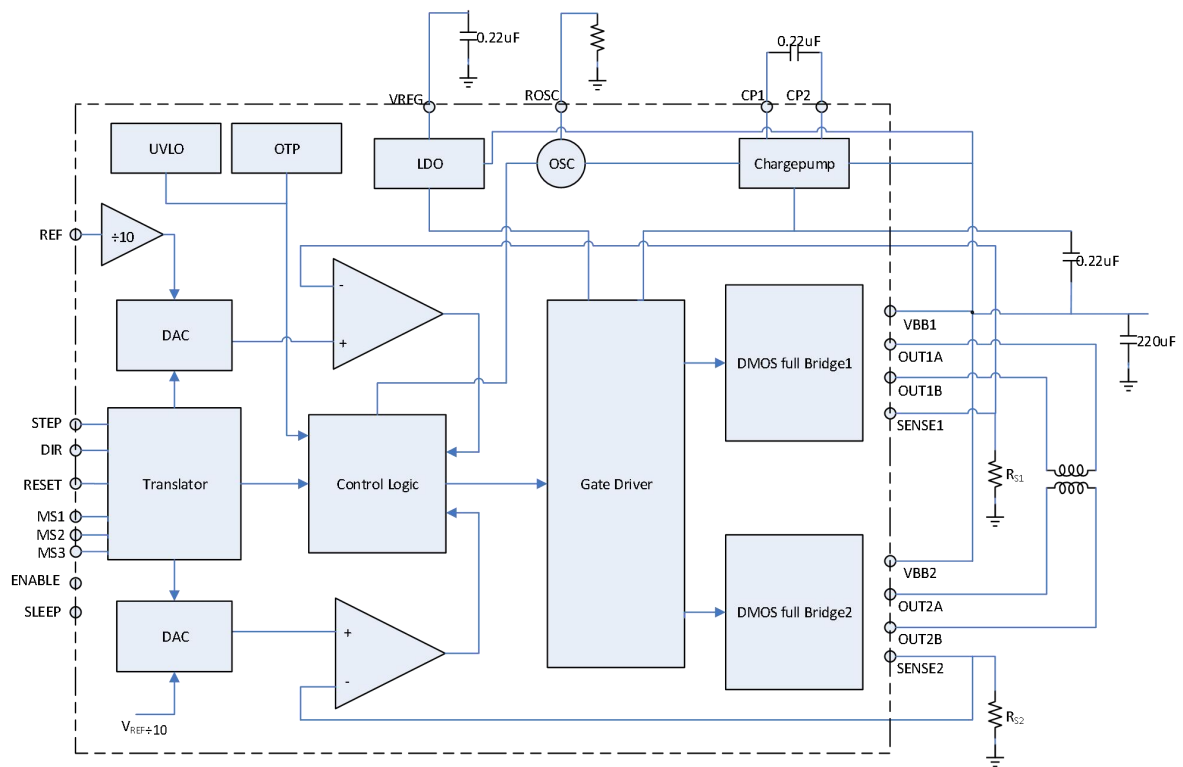
| Part Number | Package  | Marking |
|-------------|----------|---------|
| MS4998      | eTSSOP28 | MS4998  |

**PIN CONFIGURATION**


## PIN DESCRIPTION

| Pin    | Name   | Type | Description                                      |
|--------|--------|------|--|
| 1      | OUT2A  | O    | Output Channel Two, Terminal A                   |
| 2      | SENSE2 | I/O  | Output Current Detection Two                     |
| 3      | VBB2   | -    | High Voltage Load Power Supply Two               |
| 4      | OUT2B  | O    | Output Channel Two, Terminal B                   |
| 5,7,21 | GND    | -    | Ground   |
| 6      | ENABLE | I    | Output Enable                                    |
| 8      | CP1    | I/O  | Charge Pump Capacitor Terminal                   |
| 9      | CP2    | I/O  | Charge Pump Capacitor Terminal                   |
| 10     | VCP    | O    | Charge Pump Output                               |
| 11,18  | VREG   | O    | Low Voltage Power Supply Output                  |
| 12     | MS1    | I    | Step Mode Control                                |
| 13     | MS2    | I    | Step Mode Control                                |
| 14     | MS3    | I    | Step Mode Control                                |
| 15     | RESET  | I    | Reset  |
| 16     | ROSC   | I/O  | Current Decay Control                            |
| 17     | SLEEP  | I    | Sleep Mode                                       |
| 19     | STEP   | I    | Step Clock                                       |
| 20     | REF    | I    | DAC Reference Input                              |
| 22     | DIR    | I    | Forward/Reverse Mode                             |
| 23     | FG     | O    | Fault Detection Output                           |
| 24     | N.C    | -    | Not Connection                                   |
| 25     | OUT1B  | O    | Output Channel One, Terminal B                   |
| 26     | VBB1   | -    | High Voltage Load Power Supply One               |
| 27     | SENSE1 | I/O  | Output Current Detection One                     |
| 28     | OUT1A  | O    | Output Channel One, Terminal A                   |
| -      | PAD    | -    | Exposed Thermal Pad, must be connected to ground |

## BLOCK DIAGRAM



## ABSOLUTE MAXIMUM RATINGS

Any exceeding absolute maximum rating application causes permanent damage to device. Because long-time absolute operation state affects device reliability. Absolute ratings just conclude from a series of extreme tests. It doesn't represent chip can operate normally in these extreme conditions.

| Parameter                    | Symbol      | Range      | Unit |
|------------------------------|-------------|------------|------|
| VBB Voltage                  | $V_{BB}$    | 40         | V    |
| Output Current               | $I_{OUT}$   | $\pm 2$    | A    |
| Logic Input Voltage          | $V_{IN}$    | -0.3 ~ 5.5 | V    |
| Motor Output Voltage         |             | -2 ~ 37    | V    |
| SENSE Voltage                | $V_{SENSE}$ | -0.5 ~ 0.5 | V    |
| Reference Voltage            | $V_{REF}$   | 5.5        | V    |
| Operating Temperature        | $T_A$       | -40 ~ 100  | °C   |
| Maximum Junction Temperature | $T_J (MAX)$ | 150        | °C   |
| Storage Temperature          | $T_{str}$   | -55 ~ 150  | °C   |

# ELECTRICAL CHARACTERISTICS

| Parameter                         | Symbol          | Condition                            | Min                  | Typ  | Max                  | Unit        |
|-----------------------------------|-----------------|--------------------------------------|----------------------|------|----------------------|-------------|
| Load Power Supply                 | $V_{BB}$        | Operation Mode                       | 5.5                  |      | 35                   | V           |
|                                   |                 | Sleep Mode                           |                      |      |                      |             |
| On-resistance (HS)                | $R_{ON(H1)}$    | $I_O = -0.5A$                        |                      | 400  |                      | m $\Omega$  |
| On-resistance (LS)                | $R_{ON(L1)}$    | $I_O = -0.5A$                        |                      | 350  |                      | m $\Omega$  |
| Diode Forward Voltage (HS)        | $V_{D(H1)}$     | $I_D = 0.5A$                         |                      | 0.86 |                      | V           |
| Diode Forward Voltage (LS)        | $V_{D(L1)}$     | $I_D = 0.5A$                         |                      | 0.83 |                      | V           |
| Load Power Supply Current         | $I_{BB}$        | $F_{PWM} < 50kHz$                    |                      | 5    |                      | mA          |
|                                   |                 | Normal Operation,<br>Output Disabled |                      | 4.6  |                      | mA          |
|                                   |                 | Sleep Mode                           |                      | 46   |                      | $\mu A$     |
| High Input Voltage                | $V_{in(1)}$     |                                      | $0.6 \times V_{REG}$ |      |                      | V           |
| Low Input Voltage                 | $V_{in(0)}$     |                                      |                      |      | $0.4 \times V_{REG}$ |             |
| Logic Input Delay                 | $V_{HYS(IN)}$   | a % of $V_{REG}$                     | 5                    | 11   | 19                   | %           |
| Step Mode                         | $R_{MS1}$       | MS1 Pin                              |                      | 460  |                      | k $\Omega$  |
|                                   | $R_{MS2}$       | MS2 Pin                              |                      | 460  |                      |             |
|                                   | $R_{MS3}$       | MS3 Pin                              |                      | 460  |                      |             |
| Blank Time                        | $t_{Blank}$     |                                      |                      | 1.5  |                      | $\mu s$     |
| Fixed Decay Period                | $t_{Off}$       | ROSC= $V_{REG}$ or GND               | 20                   | 32   | 40                   | $\mu s$     |
|                                   |                 | ROSC=25k $\Omega$                    | 23                   | 32   | 37                   | $\mu s$     |
| REF Input Voltage                 | $V_{REF}$       |                                      | 0                    |      | 5                    | V           |
| REF Input Current                 | $I_{REF}$       |                                      |                      | <1   |                      | nA          |
| Dead Time                         | $t_{DT}$        |                                      |                      | 370  |                      | ns          |
| Thermal Shutdown                  | $T_{TSD}$       |                                      |                      | 167  |                      | $^{\circ}C$ |
| Thermal Shutdown Hysteresis       | $Y_{TSDHYS}$    |                                      |                      | 15   |                      | $^{\circ}C$ |
| <b>Built-in LDO : VREG</b>        |                 |                                      |                      |      |                      |             |
| VREG Output Voltage               | $V_{vreg}$      |                                      | 4.8                  | 5.2  | 5.4                  | V           |
| VREG Output Impedance             | $R_{vreg}$      |                                      |                      | 21   |                      | $\Omega$    |
| VREG Output Load Capacity         | $I_{outlimit}$  | VREG Drop to 4.2V                    |                      | 50   |                      | mA          |
| VREG Power Supply Rejection Ratio | $R_{VREGvsVBB}$ | VBB Input 5Hz                        |                      | 60   |                      | dB          |

## FUNCTION DESCRIPTION

### Chip Operation

The MS4998 can achieve the maximum 256 microstepping, selecting full, 1/2, 1/4, 1/8, 1/16, 1/64, 1/128, 1/256 step mode according to MSx pin. The current in two full-bridges made up of NLDMOS are regulated synchronously through PWM control circuit with fixed decay period. Each step output current depends on  $V_{REF}$ , SENSE resistance and DAC output voltage.

When power-on and reset, DAC output and phase current polarity are set as HOME state (HOME state is the 0.707 position of DAC maximum output voltage), and rectification is the mixed decay mode at each phase. When STEP command occurs, DAC output and current polarity start normal operation. The step resolution is controlled by MSx, as shown in table 1.

When stepping falls, the decay mode is mixed decay. While when stepping rises, the decay mode is slow decay. This operation mode is called automatic decay mode, which improves motor operating performance and reduce current waveform distortion caused by motor back-EMF.

### 1. Microstepping Control (MS1, MS2and MS3)

The microstepping resolution is controlled by MS1, MS2and MS3, as shown in table 1. There is a 460k $\Omega$  pullup resistor in MSx. Only after detect the rising edge of STEP signal, step mode switch is performed.

If need to change step mode, the translator is reset. Otherwise must switch on the common step position of the two step modes, in order not to lose step. When chip is power down reset due to thermal shutdown and overcurrent protection, the translator would be set as HOME state to correct all step modes.

Motor step mode truth table (IN="High"represents  $IN^+ > IN^-$ ).

Table 1. Step Mode Control Truth Table

| MS3 | MS2 | MS1 | Step Mode |
|-----|-----|-----|-----------|
| L   | L   | L   | Full Step |
| L   | L   | H   | 1/2       |
| L   | H   | L   | 1/4       |
| L   | H   | H   | 1/8       |
| H   | L   | L   | 1/16      |
| H   | L   | H   | 1/64      |
| H   | H   | L   | 1/128     |
| H   | H   | H   | 1/256     |

### 2. Reset Terminal (RESET)

When reset is valid, the translator is set as HOME state, and all output FETs are disabled. Until RESET is placed as high level, STEP signal is valid again.

### 3. STEP Input (STEP)

One step rising edge makes motor operate one microstep. Translator controls DAC output value and the current direction of each bridge leg. The microstep resolution depends on MSx.

#### 4. Direction Control (DIR)

DIR pin control motor rotation direction and starts detection when each STEP rising edge occurs.

#### 5. Internal PWM Current Control

Each full bridge is controlled by PWM circuit with fixed decay period. The circuit limits the expectation value of load current ( $I_{TRIP}$ ). At first, the diagonal high and low side FETs are enabled, then current flow through motor leg and SENSE resistor  $R_{Sx}$ . When the voltage on SENSE resistor is equal to DAC voltage, comparator clears PWM latch. The PWM latch chooses to disable appropriate FET and enter fixed period decay mode.

The maximum limiting current is determined by  $R_{Sx}$  and  $V_{REF}$ . The transconductance formula is as followed  $I_{TREP MAX} = V_{REF} / (10 \times R_S)$ .

#### 6. Fixed Off-Time

Internal PWM current control circuit uses one-shot circuit to control the duration of time that the DMOS FETs shutdown. The off-time,  $t_{off}$  depends on ROSC terminal:

ROSC connected to VREG : Current decay period is 30us, and decay mode is mixed decay for all step modes (rise slow decay, fall mixed decay);

ROSC connected to GND : Current decay period is 30us, and when current increases and decrease, decay mode is mixed decay for all step modes;

ROSC connected to GND through resistor : Decay mode is mixed decay for all step modes (rise slow decay, fall mixed decay), and decay decay period is dependant on following formula:  $T_{off} = R_{OSC} / 825$ .

#### 7. Blank Time

The reverse current, generated by parasitic diode, would cause false overcurrent detection. In order to avoid this solution, setting 1.5us blank time makes the detection signal ineffective during the period.

#### 8. Load Shorted Protection and Ground Protection

When motor loads are shorted together or directly connected to ground, the chip would detect overcurrent and disable shorted FET, avoid damage to internal devices. After shorted protection operates, it is necessary to make SLEEP high or VBB low to recover operation.

When two outputs are shorted, current flows through SENSE resistor. After 1us, the voltage on SENSE resistor meets fault condition, which makes driver enter fixed decay period. After the decay period, the driver turns on again and the process repeats. Under this condition, the driver is immune to overcurrent completely. But short circuit would last the period of time equal to fixed decay period.

#### 9. Charge Pump (CP1 and CP2)

Charge pump is used to generate the voltage more than VBB to drive high-side FET. The voltage is gradually increased through CP between CP1 and CP2, then is gradually accumulated through CG between VG and VCC. The relationship between CP and CG is as followed.

CP charge and discharge frequency is 60kHz. When CP capacitance is very large, VG would be increased. While if the capacitance is too large, charge and discharge would become inefficient and VG charge time would be very long. CP and CG are set as: CP=0.22uF, CG=0.22uF.



## 10. Output Control Power Supply VREG

The internal generated power supply is used to be as logic power supply and drive output low-side FET. It is usually set as 5.2V and 0.22uF ceramic capacitor is connected to VREG pin. If fault occurs (low voltage), the internal structure of detecting VREG would disable all outputs.

## 11. ENABLE

ENABLE can enable and disable all FETs. When ENABLE is logic 1, all FETs are at high impedance state; When ENABLE is logic 0, circuit operates normally. However, the translator input pins are constrained against ENABLE pin, such as STEP, DIR, MS1, MS2, MS3.

## 12. Shutdown

When thermal shutdown or undervoltage lockout performs, all FETs are disabled until fault is solved. When power on, undervoltage lockout also disables outputs and sets translator as HOME state.

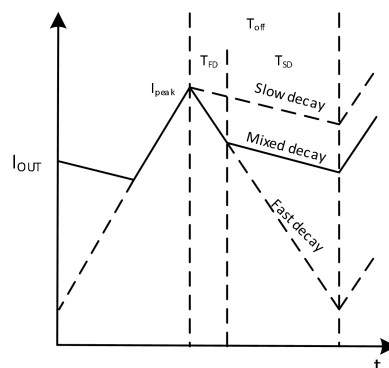
## 13. SLEEP

In order to reduce standby power dissipation, SLEEP would turn off most functions, including FETs, current regulator and charge pump. SLEEP active low and when it becomes high, chip operates normally. When motor recoveries from sleep mode, there is usually about 1ms delay time to make charge pump stable.

## 14. Mixed Decay Mode

In mixed decay mode, when current reaches the trip value, the chip would first enter fast decay mode, occupying about 31.25% of total decay period, then turns to slow decay.

In general, mixed decay is only needed to apply to current decreasing state. For most loads, adopting automatic mixed decay mode (current increasing slow decay, current decreasing fast decay) could reduce ripples caused by increasing current and avoid step loss caused by decreasing current. For some slow-speed microstepping applications, because back-EMF is very small, the load current rapidly increases and cause step loss. ROSC is tied to ground, which realizes 100% mixed decay when current increases and decreases, avoiding step loss. If without the problem, for the sake of reducing ripples, it is suggested that adopting the mixed decay mode of automatic selection.



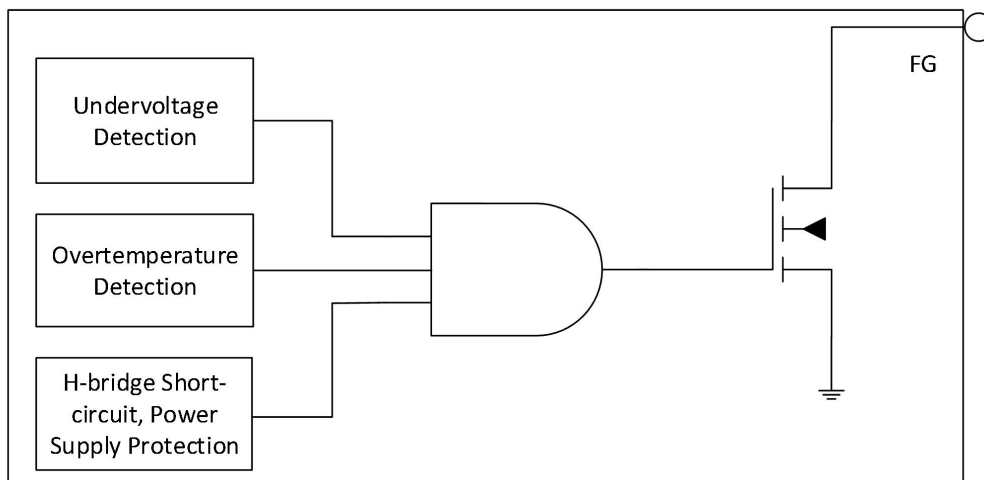
$I_{peak}$  Maximum Output Current ,  $T_{off}$  Fixed Off-time ,  $T_{SD}$  Slow Decay Time ,  $T_{FD}$  Fast Decay Time.

## 15. Synchronous Rectification

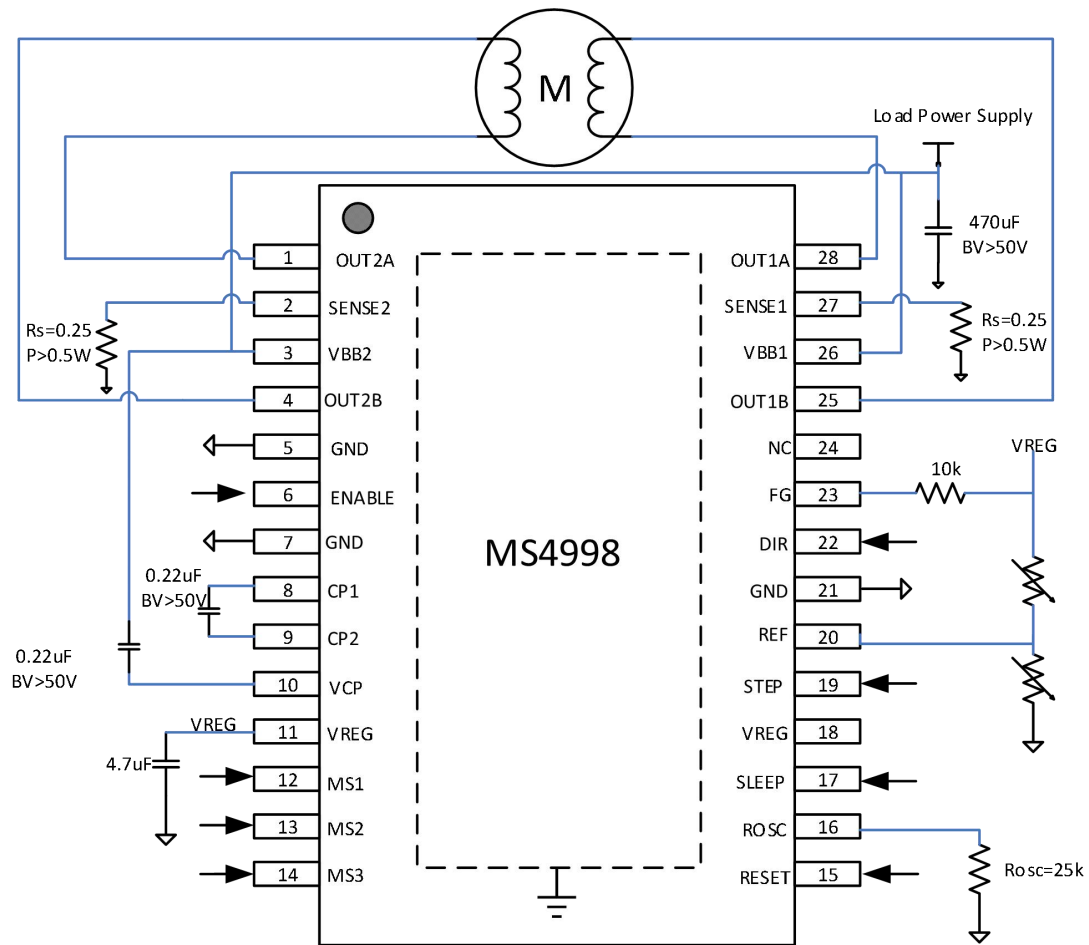
When chip enters decay period, load currents would continue flowing according to selected decay mode. The feature is that turn on appropriate FET when current decays. Low FET on-resistance shorts out the regeneration diode, which reduces power dissipation effectively and saves use of Schottky diodes in other applications. When load current approaches 0, synchronous rectification is off to prevent reverse load current.

## 16. FG Output

When detection module detects abnormal situation, FG outputs low level with open drain, and maximum pulldown current is 15mA.



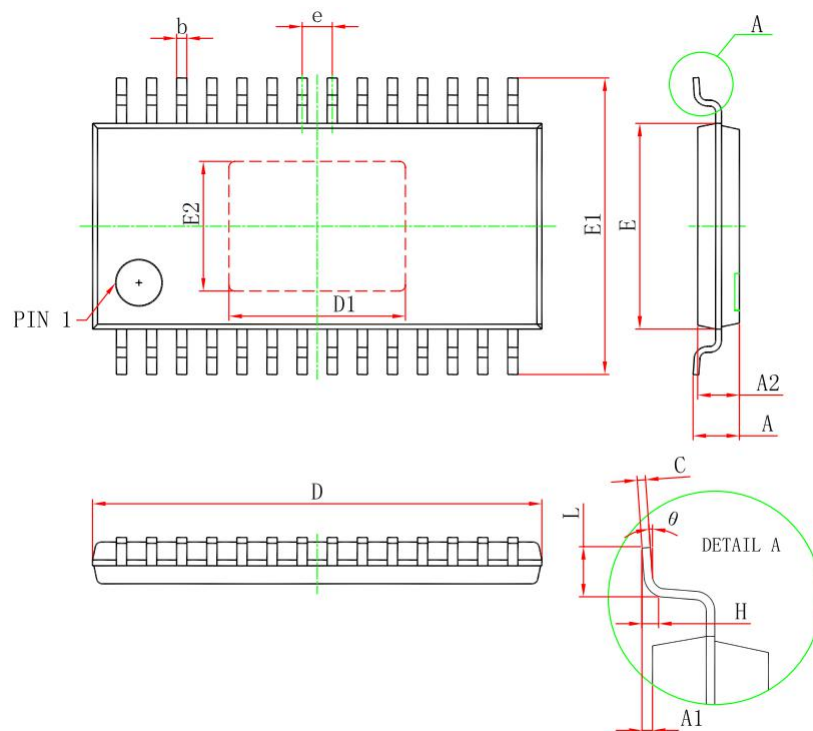
TYPICAL APPLICATION DIAGRAM



Note : The drop voltage on Rs sample resistor has better not to exceed  $\pm 0.5$ . And when current is less than 2A, it meets the most applications that Rs is equal to 0.25Ω.

# PACKAGE OUTLINE DIMENSIONS

## eTSSOP28



| Symbol | Dimensions in Millimeters |       | Dimensions in Inches |       |
|--------|---------------------------|-------|----------------------|-------|
|        | Min                       | Max   | Min                  | Max   |
| D      | 9.600                     | 9.800 | 0.378                | 0.386 |
| D1     | 3.710                     | 3.910 | 0.146                | 0.154 |
| E      | 4.300                     | 4.500 | 0.169                | 0.177 |
| b      | 0.190                     | 0.300 | 0.007                | 0.012 |
| c      | 0.090                     | 0.200 | 0.004                | 0.008 |
| E1     | 6.250                     | 6.550 | 0.246                | 0.258 |
| E2     | 2.700                     | 2.900 | 0.106                | 0.122 |
| A      |                           | 1.100 |                      | 0.043 |
| A2     | 0.800                     | 1.000 | 0.031                | 0.039 |
| A1     | 0.020                     | 0.150 | 0.001                | 0.006 |
| e      | 0.65(BSC)                 |       | 0.026(BSC)           |       |
| L      | 0.500                     | 0.700 | 0.02                 | 0.028 |
| H      | 0.25(TYP)                 |       | 0.01(TYP)            |       |
| θ      | 1°                        | 7°    | 1°                   | 7°    |

**MARKING and PACKAGING SPECIFICATIONS****1. Marking Drawing Description**

Product Name : MS4998

Product Code : XXXXXX

**2. Marking Drawing Demand**

Laser printing, contents in the middle, font type Arial.

**3. Packaging Specifications**

| Device | Package  | Piece/Reel | Reel/Box | Piece/Box | Box/Carton | Piece/Carton |
|--------|----------|------------|----------|-----------|------------|--------------|
| MS4998 | eTSSOP28 | 3000       | 1        | 3000      | 8          | 24000        |

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**MOS CIRCUIT OPERATION PRECAUTIONS**

Static electricity can be generated in many places. The following precautions can be taken to effectively prevent the damage of MOS circuit caused by electrostatic discharge:

1. The operator shall ground through the anti-static wristband.
2. The equipment shell must be grounded.
3. The tools used in the assembly process must be grounded.
4. Must use conductor packaging or anti-static materials packaging or transportation.



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